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Ni intercalation of titanium diselenide: effect on the lattice, specific heat and magnetic properties

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Abstract

Intercalated Ni_xTiSe₂ compounds with Ni concentration up to x = 0.5 have been investigated using x-ray diffraction, magnetic susceptibility and specific heat measurements. A set of peculiarities caused by the intercalation, such as a significant decrease of the gap between Se-Ti-Se trilayers and depletion of the low-frequency phonons due to the stiffening of the lattice as well as an enhancement of the density of electronic states at low Ni content (x < 0.33), is attributed to hybridization of the Ni 3d states with TiSe₂ bands and formation of covalent-like links between Se-Ti-Se trilayers via the inserted Ni ions. $Ni_x TiSe_2$ compounds with intercalant content up to x = 0.5 show a paramagnetic behaviour unlike M_r TiSe₂ compounds intercalated by other 3d metals (M = Cr, Mn, Fe, Co). The Ni magnetic moment in Ni, TiSe₂ is suggested to be of an itinerant nature. A pronounced correlation between the change of the lattice parameter c_0 and the value of the effective magnetic moment, which is observed in Ni_xTiSe₂ as well in M_xTiSe₂ systems intercalated by other 3d metals, indicates that the magnetic moment on the inserted atom is controlled by the hybridization degree of M 3d states with TiSe₂ bands.

1. Introduction

Titanium dichalcogenides TiX_2 (X = S, Se, Te), which have a layered crystal structure, have been the subject of numerous investigations because of their interesting properties; at the same time, they are very important as parent compounds for intercalation materials [1, 2]. The main feature of TiX₂ is a weak coupling between X–Ti–X trilayers via van der Waals forces.

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By the insertion of various guest M atoms into van der Waals gaps, a wide class of $M_x TiX_2$ compounds with new interesting physical properties can be obtained. The main goal of the intercalation is to synthesize materials with new functions. Among the parent compounds, much attention has been paid to the study of TiSe₂ which exhibits a charge density wave (CDW) at $T < T_t \sim 200 \text{ K} [1-4]$. The phase transition of TiSe₂ to a commensurate superlattice $(2 \times 2 \times 2)$ with a decrease in temperature below T_t was studied by various methods including the measurement of neutron diffraction [4, 5], ultrasonic velocity [6], specific heat [7] and electrical [4] and optical [8] properties. Different models such as Fermi surface nesting [4, 9], the excitonic insulator model [10] and the band Jahn–Teller effect [11] were proposed during the last few decades to explain the CDW transition in this compound. Recent re-examinations of TiSe₂ by synchrotron x-ray diffuse scattering experiments [12] and by angle-resolved photoemission with high resolution [13] have shown that the CDW transition in this compound obviously originates from electron–hole coupling together with the indirect Jahn–Teller effect, whereas, according to [14], the phonon softening observed in TiSe₂ in the vicinity of T_t [12] may also be explained within a model of the antiferroelectric instability.

Many works were devoted to the study of TiX₂ compounds intercalated by 3d-transition (M) metals. A small amount of M atoms inserted between X-Ti-X trilayers is found to suppress the formation of CDW in TiSe₂. The intercalation of 3d metals significantly modifies the lattice, electrical and magnetic properties of TiX₂ [1, 2, 15–18]. The guest M atoms usually occupy the octahedrally coordinated sites in the van der Waals gaps, resulting in contraction or expansion of the averaged interlayer distance, depending on the type of M metal and its concentration, while the intralayer spacing changes insignificantly upon intercalation. According to the band structure calculations performed for some ordered M_xTiX_2 (X = S, Se) compounds, the 3d-electron states of M ions are hybridized with TiX₂ bands [1, 18, 19]. Photoelectron spectroscopy studies performed for $M_x TiS_2$ [20, 21] and $M_x TiSe_2$ [22] systems have indeed revealed a strong hybridization of M 3d states with Ti 3d and X 3(4)p states. Moreover, the appearance of a narrow band near the Fermi level in M_xTiSe₂ compounds with M = Cr and Co [22] is observed, in comparison with the parent compound TiSe₂. Some indication of a growth of the density of electronic states (DOS) at $E_{\rm F}$, owing to the formation of such bands at the intercalation, was obtained by magnetic susceptibility [17, 23-25] and specific heat measurements [26, 27] and by spectroscopy studies [20-22].

Of the M_xTiX₂ family members, the magnetic properties were more extensively studied for M_{x} TiS₂ compounds. The existence of different magnetic states ranging from paramagnetism and spin-glass-like behaviour to states with three-dimensional magnetic order was established in TiS₂ intercalated by V, Cr, Mn, Fe, Co and Ni [28-32]. The magnetic state of these compounds was found to depend on the type and concentration of the 3d element intercalated between the X-Ti-X layers. The long-range ferromagnetic order with the easy axis parallel to the c-axis was observed in Fe_xTiS₂ at x > 0.4 [30]. The magnetic properties of the M_xTiSe₂ family are significantly less well investigated and the data presented in the different works seem to be contradictory. Thus, the magnetic susceptibility measurements performed in [17] for M_xTiSe₂ with M = V, Cr, Mn, Fe, Co, Ni and Cu at x = 0.1 and 0.2 have revealed that all these compounds are paramagnets above 4.2 K, while in other works [23, 24, 33] it has been shown that the M_x TiSe₂ compounds with M = Cr, Mn and Fe exhibit a spin-glass or clusterglass behaviour within the concentration range $0 < x \leq 0.2$. Such a discrepancy may result from a difference in the sample preparation. At a higher M content ($x \ge 0.25$), long-range antiferromagnetic order was revealed in Fe, TiSe₂ by neutron diffraction investigations [16], in contrast to the ferromagnetism of the Fe_xTiS_2 compounds. An antiferromagnetic-like behaviour was also observed in $Cr_{0.5}TiSe_2$ by magnetization and susceptibility measurements [23]. The effective magnetic moments μ_{eff} found in the literature for the 3d metals in M_xTiSe₂ are

significantly smaller than the ionic values [17, 23, 24]. Such a reduction in μ_{eff} is ascribed to the hybridization of the M 3d states with TiSe₂ bands as in the M_xTiS₂ family [17].

Systematic study of the concentration dependence of magnetic properties has been performed for relatively few M_x TiSe₂ systems. In particular, for M = Cr, Fe and Mn [23, 24, 33], it has been shown that the intercalation leads not only to a reach variety of magnetic states in a low temperature range but also causes an appreciable change of the μ_{eff} value depending on the type and content of M atoms. This behaviour clearly indicates that the M 3d–Ti 3d hybridization degree in M_x TiSe₂ depends on the atomic number of the 3d metal as in M_x TiS₂ compounds. Since there is a lack of data concerning the Ni intercalation in the literature, the present work studies the x-ray diffraction, magnetic susceptibility and specific heat of Ni_xTiSe₂ compounds in order to achieve an extended view of the effects of the 3d-metal intercalation on the main physical properties of TiSe₂.

2. Experimental details

Polycrystalline Ni_xTiSe₂ samples ($0 < x \le 0.5$) were prepared by an ampoule synthesis method from the constituent elements. The starting materials were Ti (99.9), Se (99.99) and Ni (99.9). The method of synthesis included several stages. At first, the parent compound TiSe₂ was synthesized by heat treatment of a mixture of the starting materials Ti and Se at 900 $^{\circ}$ C for 150 h. At the second stage, the mixture of Ni and TiSe₂ powders was pressed into cylinder pellets, sealed in evacuated quartz tubes and annealed at 800 °C for 1 week. The lower temperature of the second stage was chosen in order to prevent the substitution of Ni atoms for Ti atoms in the TiSe₂ matrix. The obtained specimens were milled, compacted into pellets and then homogenized under the same conditions for 1 week. Bearing in mind possible positional arrangements of Ni atoms within a layer at the intercalation [34], the samples were quenched from 800 °C by dropping the tubes into water in order to obtain samples with a random distribution of Ni atoms among accessible sites in the van der Waals gaps. Powder x-ray diffraction patterns were obtained using a DRON-4-13 diffractometer with Co K_{α} radiation. Crystal structure refinements were performed using a full-profile method (the GSAS program [35]). The unit cell parameters were determined with an accuracy of $\Delta a_0 = \pm 0.001$ Å and $\Delta c_0 = \pm 0.002 \,\text{\AA}.$

The dc magnetic susceptibility was measured by means of a Quantum Design SQUID magnetometer in the temperature interval from 2–300 K. Specific heat measurements were performed using PPMS (Quantum Design, USA) on 5–10 mg pieces of compacted powder samples.

3. Results

3.1. Crystal structure

As is seen in figure 1, the x-ray diffraction patterns for those Ni_xTiSe₂ compounds with Ni concentration up to x = 0.33 do not show any additional peaks which may be associated with either superlattice structure owing to the positional arrangement of Ni atoms and vacancies or with the presence of foreign phases. The Ni-intercalated Ni_xTiSe₂ compounds with Ni content below x = 0.33 have the same hexagonal crystal structure of the CdI₂ type (P $\overline{3}$ m1 space group) as the parent compound TiSe₂. The best fit of the experimental x-ray patterns is obtained when the intercalated atoms are situated in octahedral positions. The coordinates of the atoms in the unit cell are: Ti (0, 0, 0); Se (1/3, 2/3, z) and Ni (0, 0, 1/2). However, the insertion of Ni atoms into the van der Waals gap of TiSe₂ is found to significantly influence the lattice parameters



Figure 1. X-ray patterns for Ni_xTiSe₂ compounds with various Ni content at room temperature.

(see figure 2). The concentration dependence of the parameter c_0 shows a substantial decrease with an increase in x up to x = 0.25, while a further increase of the Ni content up to x = 0.5results in a slight growth of the c_0 value. As for the parameter a_0 , it increases monotonically with intercalation in the entire concentration range ($0 < x \le 0.5$). It should be noted that the lattice contraction along the c_0 -direction was observed over a low concentration range ($x \le 0.25$) in M_xTiSe₂ compounds intercalated by other 3d metals (Cr, Fe, Co) except Mn [24, 33, 36]. The observed decrease in c_0 and the ratio c_0/a_0 at the intercalation may originate from both the lowering of the thickness of the Se–Ti–Se trilayer (r_L) and the reduction of the gap width (r_G) between trilayers. Variation of r_L and r_G values for the Ni_xTiSe₂ system at the intercalation is displayed in figure 3. As can be seen, the gap width significantly decreases with an increase in Ni content, while the r_L value remains practically constant for $0.05 \le x \le 0.33$. These data allow us to suggest that (i) the decrease of the gap width is the main reason for the lattice contraction of Ni_xTiSe₂ along the *c*-direction with an increase in *x* and (ii) the geometry of the Se surrounding of Ti atoms does not change appreciably at the intercalation.

An increase of the intercalant content above x = 0.33 leads to a change of the crystal structure as can be seen on examination of the x-ray diffraction pattern for Ni_{0.5}TiSe₂ (figure 1). The crystal structure of this compound may be described quite well (with $R_w = 6\%$) as being of a monoclinic type (space group I 2/m) with unit cell parameters $a_0 = 6.161(1)$ Å, $b_0 = 3.567(1)$ Å, $c_0 = 11.836(2)$ Å and $\beta = 90.29(3)^\circ$. This structure may result from the



Figure 2. Variations of the lattice parameters a and c with the Ni concentration in Ni_xTiSe₂ compounds.



Figure 3. Concentration dependence of the thickness of the Se–Ti–Se trilayer and the width of the van der Waals gap in the $Ni_x TiSe_2$ system.

ordering of Ni atoms in a superlattice, $\sqrt{3}a_0 \times a_0 \times 2c_0$. The change in the crystal structure above x = 0.33 is accompanied by growth of the unit cell volume (figure 2(b)). It should be noted that the same kind of superstructure ($\sqrt{3}a_0 \times a_0 \times 2c_0$) caused by an ordering of intercalated Fe atoms and vacancies was found to exist at x = 0.5 in the Fe_xTiSe₂ series [37].

3.2. Magnetic susceptibility

Figure 4(a) displays the temperature dependences of the magnetic susceptibility for Ni_xTiSe₂ compounds. The susceptibility of the parent compound TiSe₂ reveals weak temperature dependence above ~100 K and a low-temperature upturn of the Curie–Weiss (CW) type. At middle temperatures, the susceptibility has a negative sign, which is associated with the presence of the diamagnetic contribution from the ions with fully filled electron shells. After subtraction of the CW term from the $\chi(T)$ dependence for TiSe₂, one can observe an anomalous change of the contribution associated with paramagnetic behaviour of the conduction electrons (shown in the inset to figure 4(a)), i.e., the Pauli paramagnetic contribution χ_p . The critical temperature $T_t \approx 200$ K, at which a substantial reduction of the CDW. Our data for TiSe₂ are in good agreement with previous results [4]. As was suggested in [4], the presence of the low-temperature CW contribution to the total susceptibility of TiSe₂ may result from magnetic impurities.

The intercalation of Ni atoms into the van der Waals gaps of the TiSe₂ matrix is found to increase the low-temperature upturn and modify the high-temperature form of the susceptibility. According to our data, all Ni_xTiSe₂ compounds with Ni content up to x = 0.5 remain paramagnetic with decreasing temperature down to 2 K. The effect of the Ni intercalation is more clearly seen in figure 4(b) which displays the temperature dependence of the inverse susceptibility of the compounds with various Ni content. Thus, the temperature dependence of χ for Ni_xTiSe₂ is suggested to include two temperature-dependent contributions:

$$\chi(T) = \frac{C}{T - \theta_{\rm p}} + \chi_0(T). \tag{1}$$

The first contribution in (1) is of the CW type, which dominates in the low-temperature region (<100 K), and the second term involves both the temperature-dependent Pauli paramagnetic contribution from conduction electrons and the diamagnetic contribution, i.e. $\chi_0(T) = \chi_p(T) + \chi_d$. Figure 4(c) shows the inverse susceptibility $(\chi - \chi_d)^{-1}$ for the parent TiSe₂ after subtraction of the temperature-independent diamagnetic contribution $\chi_d = 0.52 \times 10^{-6}$ emu g⁻¹ Oe⁻¹ [23] for comparison. The temperature dependences of the inverse susceptibility for Ni_xTiSe₂ show a pronounced non-monotonic character owing to the competition of two temperature-dependent contributions in (1), unlike the $\chi^{-1}(T)$ curves for the compounds intercalated by other 3d metals, which are nonlinear but monotonic above their ordering temperatures (see [23, 24], for example), since for M_xTiSe₂ (M = Cr, Fe, Mn, Co) the first term in (1) significantly surpasses the second one. As it turned out, the temperature dependence of the magnetic susceptibility of Ni_xTiSe₂ compounds may be described by the expression

$$\chi(T) = \frac{C}{T - \theta} + \chi_{\rm d} + \chi_{\rm p0} - PT^2, \qquad (2)$$

where χ_{p0} and *P* are constants. The best-fitting results are presented in figure 4(b) (solid line). As can be seen, the experimental data agree with this expression quite well in the entire temperature interval; however, some discrepancy in the low-temperature range is observed for the compound with x = 0.33. Using equation (2), the effective magnetic moment μ_{eff} , paramagnetic Curie temperature θ_p , parameter *P* and the sum ($\chi_d + \chi_{p0}$) were determined for each compound. The last was obtained by extrapolation of the $\chi_0(T)$ curves presented in the inset to figure 4(a) to T = 0. All these data are collected in table 1. The effective magnetic moment per Ni ion in Ni_xTiSe₂ compounds is found to be significantly lower than $\mu_{eff}^{calc} = 2.83\mu_B$ for the free Ni²⁺ ion as was observed for M_xTiX₂ compounds intercalated by other 3d metals. The maximal value of $\mu_{eff} = 0.3\mu_B$ is obtained for x = 0.1; with further growth



Figure 4. (a) Temperature dependence of the magnetic susceptibility of Ni_xTiSe₂ at various Ni content (inset shows the temperature dependence of χ_0 for Ni_xTiSe₂ after subtraction of the CW contribution from the total susceptibility); (b) χ^{-1} versus *T* curves for Ni-intercalated compounds (solid lines correspond to fitting by expression (2)); and (c) $(\chi - \chi_d)^{-1}$ versus *T* dependence for the parent compound TiSe₂.

of the Ni content, the value of μ_{eff} decreases and remains almost unchanged $(0.16\mu_{\text{B}}-0.18\mu_{\text{B}})$ within the concentration range $0.25 \le x \le 0.5$. The θ_{p} of those compounds with Ni content $x \le 0.33$ is estimated to be about -1 K, which implies an insignificance of the Ni–Ni exchange interaction over this concentration range. All values of μ_{eff} presented in table 1 are slightly

Table 1. The effective magnetic moment μ_{eff} per Ni atom, the paramagnetic Curie temperature θ_p , the sum $(\chi_d + \chi_{p0})$ of the diamagnetic and Pauli paramagnetic contributions to the total magnetic susceptibility (obtained by extrapolation of χ_0 to T=0), the coefficient *P* of the T^2 term in expressions (2) and (3) and the coefficient γ of the electronic contribution to the total specific heat, for Ni_xTiSe₂ compounds with various Ni content.

X	μ_{eff} (μ_{B})	θ _p (K)	$\chi_d + \chi_{p0}$ (10 ⁻⁷ emu g ⁻¹ Oe ⁻¹)	Р (К ⁻²)	γ (mJ g-at. ⁻¹ K ⁻²)
0	_	_	-0.4	_	0.3
0.1	0.3	-1.3	1.2	-4.55×10^{-13}	_
0.25	0.17	-1.5	0.28	-1.18×10^{-12}	2.1
0.33	0.16	-1.0	~ 0.00	-1.06×10^{-12}	1.4
0.5	0.18	-4.6	1.9	-9.94×10^{-13}	1.9

overestimated because we did not take into account the small contribution arising from impurities in the TiSe₂ matrix. Subtraction of the CW contribution caused by impurities in the parent compound TiSe₂ from the total susceptibility of Ni_xTiSe₂ leads to a decrease of the effective magnetic moment per Ni atom by about $0.05\mu_B$. This value seems to be quite large for Ni_xTiSe₂ compounds because of the low values of μ_{eff} for the Ni ion; nevertheless, we suppose that this additional contribution does not significantly influence the character of the concentration dependence of μ_{eff} , since in the present work we have used the same parent matrix TiSe₂ for the synthesis of all Ni-intercalated compounds.

As one can see from the inset to figure 4(a), the second contribution in (1), which was obtained after subtraction of the CW term, reveals gradual growth with an increase in temperature for all intercalated Ni_xTiSe₂ compounds as well as for TiSe₂. There are no indications of the appearance of CDW in the Ni_xTiSe₂, even at x = 0.1. This result is in agreement with other studies [4, 23], which showed that the intercalation of d metals suppresses the superlattice formation in TiSe₂. As follows from estimations in [23], the diamagnetic contribution to the total magnetic susceptibility of M_xTiSe₂ should not change significantly upon intercalation. Therefore the change of χ_0 with the Ni content and with the temperature may be associated mainly with a change in the paramagnetic contribution from the conduction electrons χ_p . It should be noted that the pronounced temperature dependence of the magnetic susceptibility was found to exist in many d-transition metals that do not possess magnetic order [38]. Such a temperature dependence of χ_p is associated with the change in the DOS value $N(E_F)$ at E_F and its first N' and second N'' derivatives [38]:

$$\chi_{\rm p} = \mu_{\rm B}^2 N(E_{\rm F}) \left\{ 1 - \frac{\pi^2 k_{\rm B}^2}{6} \left[\left(\frac{N'}{N} \right)^2 - \left(\frac{N''}{N} \right) \right]_{E=E_{\rm F}} T^2 \right\} = \chi_{\rm p0} - P T^2.$$
(3)

As follows from table 1, the intercalation of Ni is accompanied by a non-monotonic change of $\chi_0(T=0) = (\chi_d + \chi_{p0})$; at first (up to x = 0.1), this value increases significantly and reaches the value $\sim 1.2 \times 10^{-7}$ emu g⁻¹ Oe⁻¹ which agrees quite well with the Pauli contribution obtained for Ni_{0.1}TiSe₂ by Tazuke and Takeyama [17]. However, according to our data, the value of χ_0 increases with an increase in temperature, whereas, in [17], such a contribution was suggested to be temperature-independent. An increase of the Ni content up to x = 0.33 is accompanied by lowering of $\chi_0(T=0)$, while further intercalation leads to the growth of $\chi_0(T=0)$ up to $\sim 1.9 \times 10^{-7}$ emu g⁻¹ Oe⁻¹ at x = 0.5. It should be mentioned that unlike Ni_xTiSe₂ compounds, for which an appreciable growth of χ_0 is observed, the paramagnetic contribution from conduction electrons to the total magnetic susceptibility of M_xTiSe₂ compounds intercalated



Figure 5. Temperature dependence of the specific heat for TiSe₂. The solid line corresponds to the lattice contribution calculated in the Debye model with $\Theta_D = 203$ K. Inset: C_p/T versus T^2 dependence.

by other 3d metals (M = Cr, Mn, Fe, Co) was suggested to be temperature-independent [23, 24, 33, 36]. In our opinion, the last may be caused by the fact that the temperature dependence of χ_0 is masked in this case by the large CW term and, therefore, cannot be revealed so distinctly as in the Ni_xTiSe₂ system.

3.3. Heat capacity

Figure 5 shows the temperature dependence of the specific heat for the parent compound $TiSe_{2}$. As it turned out, at low temperatures (<7 K), the C_p versus T curve can be well described by the well-known expression $C_{\rm p}(T) = \gamma T + \beta T^3$ (see inset to figure 5). For the temperature interval 2–7 K, the electronic specific coefficient γ is estimated to be about 0.3 mJ g-at.⁻¹ K⁻² and the Debye temperature Θ_D is found to be ~203 K. Our γ value is larger than that obtained in [7] for a powder sample ($\gamma = 0.18$ mJ g-at.⁻¹ K⁻²). Although the error in our estimation of γ is rather large due to the small γ value, such a discrepancy may be attributed to differences in the sample preparation. The low electronic contribution to the total specific heat of TiSe₂ is associated with the presence of the above-mentioned CDW state in this compound. Using the value $\Theta_{\rm D} = 203$ K, we did not succeed in the description of the experimental $C_{\rm p}(T)$ dependence over the entire temperature range (2-250 K). The increase in the specific heat of TiSe₂ above 7 K is more gradual than would be expected for a simple Debye model with a temperature-independent effective Debye temperature. This is clearly seen from figure 5, where the calculated lattice contribution for $\Theta_{\rm D} = 203$ K is shown by the broken line. Our heat capacity measurements on the compacted powder sample of TiSe₂ did not reveal any anomaly around 200 K, which can be associated with the phase transition from the superlattice state with CDW to the normal state with increasing temperature, while such a transition was demonstrated by the measurements of the magnetic susceptibility (figure 4) and electrical resistivity [39] on the powder sample synthesized by the same method. It should be noted that a small anomaly of the specific heat at $T \approx 200$ K was observed in an earlier work [7] on a small single crystal with a mass of ~ 0.3 mg.

Figure 6 displays the $C_p(T)$ dependences for Ni_xTiSe₂ in the temperature interval from 2–100 K. The low-temperature part of the $C_p(T)$ dependence for x = 0 is also presented in this



Figure 6. Temperature dependence of the specific heat for intercalated Ni_xTiSe₂ compounds.



Figure 7. C_p/T versus T^2 for Ni_xTiSe₂ at various Ni content.

figure for comparison. As can be seen, the intercalation of Ni ions leads to appreciable change of the lattice contribution to the heat capacity. At first, the increase of the Ni concentration up to x = 0.33 decreases the lattice contribution, while further growth of the Ni content results in an increase of the lattice contribution. As in the case of the pure TiSe₂ compound, we could not describe the phonon contribution to the $C_p(T)$ dependences for Ni_xTiSe₂ in the Debye model with a temperature-independent value of Θ_D . In order to evaluate the electronic contribution to the specific heat, we plotted in figure 7 the C_p/T versus T^2 curves in the low-temperature region. The values of γ are presented in table 1. The intercalation of Ni up to x = 0.25 results in growth of the γ value. An enhancement of the γ value at the 3d-metal intercalation was also observed in M_xTiS₂ compounds [26]. However, within the M_xTiS₂ series, the growth of γ in the case of Ni intercalation is not so substantial as in the case of intercalation by other 3d metals. An analogous situation may be expected for M_xTiSe₂ systems. The increase of the Ni concentration above x = 0.25 leads to a non-monotonic change of γ within the interval 1.4–2.1 mJ g-at.⁻¹K⁻². Another feature which can be seen in figure 7 is the flattening or small



Figure 8. (a) Concentration dependences of (a) the lattice parameter *c* and (b) the effective magnetic moment μ_{eff} per M ion for $M_x \text{TiSe}_2$ systems with M = Cr, Mn, Co and Ni.

upturn of C_p/T versus T^2 dependences for Ni_xTiSe₂ when the temperature decreases below 4 K. A pronounced upturn of the C_p/T versus T^2 curves over the low-temperature range was also observed for some M_xTiS₂ in [26, 27], where different models (spin fluctuation model, Schottky contribution and others) are considered, which could be used for the explanation of such a behaviour. Further investigations are needed in order to determine the origin of this phenomena.

4. Discussion

Although the band structure calculations were made for ordered crystal structures of $M_x TiX_2$ compounds, one can assume that the results of these calculations are also applicable to the compounds with randomly distributed M ions in the layers between X–Ti–X trilayers. According to the calculations [18, 19], the hybridization degree as well as the position of the M 3d band is expected to depend on the type of inserted M ions. The hybridization of M 3d states with $TiSe_2$ bands should lead to a loss of the ionic character of the inserted M atoms and may result in a significant lattice distortion owing to the intercalation.

In order to reveal how the type of the M metal influences the lattice at the intercalation, we plotted in figure 8(a) the x dependence of the lattice parameter c_0 for Ni_xTiSe₂ as well as for other M_xTiSe₂ compounds intercalated by M = Cr [23], Mn [24] and Co [36]. As can be seen, the intercalation of Cr with the partially occupied majority subband, as well as the

intercalation of Co and Ni with the partially occupied minority subband, leads to a decrease in the lattice parameter c_0 with increasing intercalant content up to x = 0.25. The contraction of the lattice observed in the *c*-direction may be associated with the bonding effect arising from the formation of covalent-like links between X–Ti–X layers via intercalated M ions. Since, for M = Ni or Co, the reduction of the c_0 parameter is more significant than in the case of the Cr intercalation, one can suggest a stronger degree of hybridization of Ni and Co 3d states with Ti 3d and Se 4p states in comparison with Cr. As for the Mn_xTiSe₂ system, the increase in the c_0 parameter owing to the Mn intercalation may be indicative of a lower hybridization effect in the case of the half-filled 3d-electron band of intercalated 3d metals [24]. Further increase of the M concentration up to x = 0.5 is accompanied by a growth of the c_0 parameter in the case of M = Cr and Ni, while the c_0 parameter remains practically constant for M = Mn and decreases more slowly at the intercalation of Co. Such a behaviour of $c_0(x)$ in M_xTiSe₂ at x > 0.25 may be attributed to the saturation of the covalent-like links in these intercalated compounds [36].

In figure 8(b), we present the effective magnetic moment μ_{eff} per M ion versus the concentration of inserted atoms for the same M_xTiSe₂ systems. All these data were obtained by using the expression (1) without taking into account a possible contribution from impurities in the matrix as was made in the present work. Comparison of $\mu_{eff}(x)$ for M = Cr, Mn and Co with that obtained in the present work for Ni_xTiSe₂ shows that, in all these systems, the value of μ_{eff} is significantly lower than that for free M ions; moreover, a pronounced correlation between $\mu_{\text{eff}}(x)$ and $c_0(x)$ exists: the decrease in c_0 with an increase in intercalant content up to $x \sim 0.25$ in the case of M = Cr, Co or Ni is accompanied by a decrease of $\mu_{\rm eff}$, whereas both c_0 and $\mu_{\rm eff}$ values show growth with the intercalation of Mn over the low-concentration range. In our opinion, such a correlation indicates that the value of $\mu_{\rm eff}$ in M_xTiSe₂ compounds is controlled by the hybridization degree of the M 3d and Ti 3d states. These findings imply an itinerant nature of the magnetic moment of the M ions intercalated. The presence of the CW-type contribution in the itinerant d-electron magnets is associated with the temperature dependence of the local amplitude of spin fluctuations [40]. As additional evidence of the itinerant character of magnetism in the $M_x TiX_2$ compounds, one may consider the results of high-field magnetization measurements performed at low temperatures for some intercalated compounds $Cr_{0.5}TiSe_2$ [23], Cr_xTiTe_2 [25] and Fe_xTiS_2 [31]. In these compounds, the magnetic moment per intercalated guest atom in saturation, μ_s , is found to be appreciably lower than the saturation moment value calculated from the localized moment model and lower than the effective magnetic moment obtained from the paramagnetic susceptibility measurements. One can evaluate the Rhodes–Wohlfarth ratio $\mu_{\rm eff}/\mu_{\rm S}$ which is usually used for characterizing spinfluctuation systems [40]. Taking the values of $\mu_{eff} = 4.0\mu_B$ [33] and $\mu_S = 2.55\mu_B$ [31], we estimated this ratio for Fe_{0.33}TiSe₂ as 1.56. The same value of the μ_{eff}/μ_{S} ratio was obtained for the $Cr_{0.5}TiSe_2$ compound (see [23]). These data allow us to suggest that the physical properties of TiX₂ compounds intercalated by 3d metals are appreciably influenced by spin fluctuations. This assumption is supported by specific heat measurements [26] which show that the value of the electronic specific heat coefficient γ for $M_{x}TiS_{2}$ is appreciably enhanced in comparison with the theoretical value. Unfortunately, we did not reach a saturation of the magnetization for Ni, TiSe₂ compounds at T = 2 K in the magnetic field used in the present work (50 kOe) and, therefore, we could not evaluate the $\mu_{\rm eff}/\mu_{\rm S}$ ratio in this case. Nevertheless, bearing in mind the data obtained for isostructural M_xTiX₂ compounds, one can suppose that the CW-type contribution to the total magnetic susceptibility of Ni_xTiSe₂ originates from the temperature dependence of the local amplitude of spin fluctuation in the Ni 3d-electron subsystem as well as in M_xTiX₂ compounds intercalated by other 3d metals. Despite forming a band and hybridization with Ti 3d and Se 4p electrons, the 3d electrons of inserted M atoms seem not to be fully delocalized in M₂TiSe₂. This follows from recent studies of the magnetic circular dichroism for isostructural $Fe_x TiS_2$ compounds [41]. As it turned out, the total magnetic moment of Fe ions inserted into the TiS_2 matrix includes an appreciable contribution from the orbital angular momentum. This orbital contribution is found to decrease with an increase in intercalant content, which implies a change of the delocalization degree of M 3d electrons upon intercalation.

As can be seen from table 1, both the sum $(\chi_d + \chi_{p0})$ and the electronic specific heat coefficient γ for Ni_xTiSe₂ reveal an analogous behaviour for the Ni intercalation, i.e., significant growth on increasing x up to x = 0.1 - 0.25 and their non-monotonic change on further intercalation. Such a correlation seems unsurprising, since both χ_{p0} and γ are proportional to the density of electronic state at the Fermi level and may be enhanced by the contribution of spin fluctuations. There are several factors which may determine such a complicated concentration dependence of χ_{n0} and γ in Ni, TiSe₂: (i) the disappearance of the energy gap associated with the CDW state in the parent TiSe₂; (ii) the formation of the additional band near the Fermi level; (iii) the appearance of an additional contribution from spin fluctuations in the 3d-electron subsystem of inserted ions; (iv) the shift of the position of the Fermi level owing to growth in the concentration of the s and d electrons which are put into TiSe₂; (v) variations of the Ni 3d-Ti 3d hybridization and the lattice parameters; and (vi) the change of the crystal structure at a high Ni content ($x \sim 0.5$). The increase of χ_{p0} and γ values with the Ni intercalation over a low-concentration range (x < 0.25) may be attributed to the first two reasons, while their further non-monotonic change with an increase in x is not understood yet. It should be noted that the value of $\chi_0(T=0) = 1.2 \times 10^{-7}$ observed in the present work for Ni_{0.1}TiSe₂ is lower than that obtained from the magnetic susceptibility measurements for M_{0.1}TiSe₂ compounds intercalated by other 3d metals: $\chi_0 = 15 \times 10^{-7}$ for M = Mn [24]; 4.3×10^{-7} for M = Fe [36]; and 2.3×10^{-7} for M = Co [36] (all data are in emu g⁻¹ Oe⁻¹). These data suggest a decrease of DOS with an increase in atomic number of the 3d metal intercalated in M, TiSe2, which is in agreement with band structure calculations performed for isostructural $M_x TiS_2$ compounds [18]. The growth of the paramagnetic contribution from conduction electrons with increasing temperature observed for all Ni, TiSe₂ compounds (shown in the inset to figure 4) is associated with the negative sign of the coefficient P in expressions (2) and (3). Such a temperature dependence of χ_p may result from the temperature dependence of the Fermi energy. It should be noted that a strong temperature dependence of $E_{\rm F}$ was derived from the calculations [14] for TiSe₂ at $T > T_t$, where the magnetic susceptibility of this compound increases with an increase in temperature.

Let us consider the change in the lattice contribution to specific heat and phonon dynamics observed in Ni, TiSe₂. At first sight, one may assume that the low-temperature specific heat for Ni_xTiSe₂ should obey the T^2 or T^n power law (2 < n < 3) owing to its layered crystal structure as for graphite [42]. However, because of a significantly higher value of the shearing elastic constant for TiSe₂ ($C_{44} = 14.3 \times 10^{10}$ dyn cm⁻² [5]) compared with graphite (4.6×10^{10} dyn cm $^{-2}$ [43]), this compound can be considered to be of a three-dimensional nature. Thus the low-temperature specific heat of TiSe₂ and Ni_xTiSe₂ should obey the T^3 law, as is observed below 7 K (figure 7). The intercalated Ni_xTiSe₂ compounds should have a higher degree of three-dimensionality owing to the bonding effect through Ni atoms. One may suggest that, at T > 7 K, the deviation of the experimental $C_{\rm p}(T)$ curves from that calculated from the simple Debye model originates from a strong anisotropy in the acoustic modes in TiSe₂[5]. The $C_{\rm p}(T)$ dependence for TiSe2 at higher temperatures may also be influenced by the phonon softening which was revealed in a wide temperature range around the CDW transition [12]. It should be noted that a widely used way to describe the lattice contribution to the total specific heat is to combine both the Debye term of the acoustic phonon mode and the Einstein term of the optical mode. However, this method can scarcely be applied for TiSe₂ in the low-temperature region,



Figure 9. Phonon spectrum derived from specific heat data for $Ni_x TiSe_2$. Inset shows the concentration dependence of PhDOS at $\nu = 1$ and 2.8 THz.

since, as follows from the experimental data and calculations [12, 44], the contribution to the heat capacity from optical phonons should be important in this case at temperatures $\gtrsim 100$ K. The change of the lattice contribution to the specific heat observed in Ni_xTiSe₂ compounds at the Ni intercalation (figure 6) may be attributed to a modification of the phonon spectrum owing to the Ni 3d–Ti 3d hybridization and formation of covalent links between Se–Ti–Se trilayers via the Ni atoms inserted. We made an attempt to obtain the phonon spectrum directly from our specific heat data for Ni_xTiSe₂ using the method proposed by Chen based on a new theorem of the Möbius inverse formula [45]. As shown in [46], by applying this method to YBCO a phonon spectrum can be obtained that agrees quite well with inelastic neutron scattering data.

The phonon contribution $C_{\rm ph}$ to the total specific heat of Ni_xTiSe₂ was obtained after subtraction of the electronic contribution $C_{\rm el} = \gamma T$. Neglecting the difference between $C_{\rm p}$ and $C_{\rm v}$, the specific heat associated with the lattice vibration can be expressed as

$$C_{\rm ph}(T) = rk \int_0^\infty \frac{(h\nu/kT)^2 \,\mathrm{e}^{h\nu/kT}}{(\mathrm{e}^{h\nu/kT} - 1)^2} G(\nu) \,\mathrm{d}\nu \tag{4}$$

where *r* is the number of atoms per formula unit, $G(\nu)$ is the phonon density of states (PhDOS) and other symbols have their usual meaning. For our analysis, we have chosen a lowtemperature interval (up to 80 K), where the $C_{ph}(T)$ dependence is mainly determined by acoustic phonons. The $G(\nu)$ dependences calculated for Ni_xTiSe₂ compounds are presented in figure 9 for frequencies up to 3 THz which correspond to acoustic vibrations [12, 44]. In the low-frequency region, the Debye relation $G \propto \nu^2$ is found to dominate for TiSe₂ and for all intercalated compounds, while the value of PhDOS decreases significantly owing to the Ni intercalation. We attribute such a behaviour to stiffening of the lattice due to the bonding effect caused by the insertion of Ni atoms. The change of PhDOS with the Ni concentration at low ($\nu = 1$ THz) and high ($\nu = 2.8$ THz) frequencies is shown in insets to figure 9. As it turned out, at low frequencies, PhDOS decreases more significantly with an increase in *x* up to x = 0.5 when compared with high frequencies. The ratio of G(x = 0)/G(x = 0.5) is estimated to be ~2.36 for $\nu = 1$ THz, while it reaches only 1.37 for $\gamma = 2.8$ THz. Moreover, the $G(\nu)$ dependences for x = 0.33 and 0.5 reveal a crossover at $\nu \sim 2.8$ THz, which may be associated with the above-discussed change of the crystal structure from the CdI₂ type at $x \le 0.33$ to the monoclinic one at x > 0.33.

5. Conclusion

X-ray diffraction study of the crystal structure and measurements of the magnetic susceptibility and specific heat performed in the present work for the intercalated Ni_xTiSe₂ compounds have shown that the intercalation significantly modifies their main physical properties. The intercalation of Ni atoms between Se–Ti–Se trilayers substantially decreases the lattice parameter c_0 and increases the inter-atomic distances in the perpendicular direction. It has been shown that the contraction of the lattice in the *c*-direction is caused by a decrease of the van der Waals gap width, which is attributed to the formation of covalent links between Ni 3d and Se 4p orbitals and to the Ni 3d–Ti 3d hybridization. As follows from the phonon spectrum derived directly from the specific heat data for Ni_xTiSe₂ using the method proposed by Chen [28], the additional bonding effect and stiffening of the lattice at the Ni intercalation lead to the substantial depletion of low-frequency lattice vibrations. Inelastic neutron scattering experiments are needed to confirm this result.

A comparative analysis of the lattice and magnetic properties of NirTiSe₂ compounds and other M_xTiSe₂ systems has revealed a pronounced correlation between the concentration dependence of the lattice parameter c_0 and the effective magnetic moment per M ion. The value of $\mu_{\rm eff}$ for Ni as well as for other M metals intercalated in M_xTiSe₂ is found to be significantly lower than that expected for the free M ions. These data allow us to suggest that the value of $\mu_{\rm eff}$ is strongly dependent on the M 3d–Ti 3d hybridization degree. The hybridization degree is suggested to increase with an increase in atomic number of the 3d metal intercalated. This suggestion is supported by the data on the Pauli paramagnetic contribution to the total magnetic susceptibility, which indicate that the DOS value at the Fermi level in $M_x TiSe_2$ decreases with an increase in Z. This last result may also be indicative of a shift of the position of M 3delectron states towards low energies when the M atomic number increases. We consider all these findings as proof of the itinerant nature of the magnetic moment of 3d-transition metal ions intercalated in the TiSe₂ matrix. The value of the effective magnetic moment per M ion in M_{ν} TiSe₂ is expected to be determined by the amplitude of the local spin density and spatial extension of the spin correlation [40], which are apparently dependent on the type and concentration of the M metal as well as on the hybridization degree of M 3d states with TiSe₂ bands.

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